

WS3A020120K

Silicon Carbide Schottky Diode

V_{RRM} = 1200 V $I_F(T_C \le 135^{\circ}C)$ = 26 A** Q_C = 58 nC**

Features

- Zero Reverse Recovery Current
- Zero Forward Recovery Voltage
- Positive Temperature Coefficient on V_F
- Temperature-independent Switching
- 175°C Operating Junction Temperature

Benefits

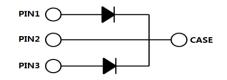
- Replace Bipolar with Unipolar Device
- Reduction of Heat Sink Size
- Parallel Devices Without Thermal Runaway
- Essentially No Switching Losses

Applications

- Switch Mode Power Supplies
- Power Factor Correction
- Motor drive, PV Inverter, Wind Power Station

Package



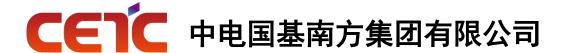


Part Number	Package	Marking
WS3A020120K	TO-247-3	WS3A020120K

Maximum Ratings

Symbol	Parameter	Value	Unit	Test Conditions	Note
V_{RRM}	Repetitive Peak Reverse Voltage	1200	V	T _C = 25°C	
V_{RSM}	Surge Peak Reverse Voltage	1200	V	T _C = 25°C	
V_{R}	DC Blocking Voltage	1200	V	T _C = 25°C	
l _F	Forward Current (Per leg/Device)	30/60 13/26 10/20	А	$T_C \le 25^{\circ}C$ $T_C \le 135^{\circ}C$ $T_C \le 149^{\circ}C$	
I _{FSM}	Non-Repetitive Forward Surge Current	95*	Α	$T_C = 25^{\circ}C$, $t_p = 8.3$ ms, Half Sine Wave	
P _{tot}	Power Dissipation (Per leg/Device)	150/ 300	W	$T_C = 25^{\circ}C$	Fig.3
T _C	Maximum Case Temperature	149	°C		
T_J, T_{STG}	Operating Junction and Storage Temperature	-55 to 175	°C		
	TO-247 Mounting Torque	1	Nm	M3 Screw	

^{*}Per Leg, **Per Device



Electrical Characteristics (Per Leg)

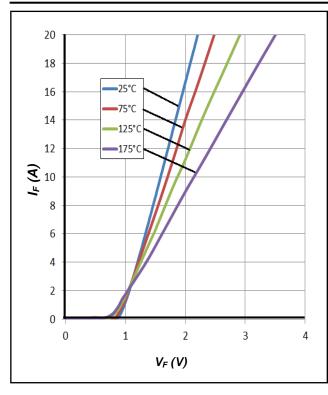
Symbol	Parameter	Тур.	Max.	Unit	Test Conditions	Note
V	Command Valtage	1.55	1.8	V	I _F = 10A, T _J = 25°C	F: ~ 4
V_{F}	Forward Voltage	2.2	2.5	V	I _F = 10A, T _J = 175°C	Fig.1
,	Davis Comment	2	20		V _R = 1200V, T _J = 25°C	F: 0
I _R	Reverse Current	10 200	μA	V _R = 1200V, T _J = 175°C	Fig.2	
		650			$V_R = 0V, T_J = 25^{\circ}C, f = 1MHz$	
С	Total Capacitance	49	/	pF	$V_R = 400V, T_J = 25^{\circ}C, f = 1MHz$	Fig.5
		40			$V_R = 800V, T_J = 25^{\circ}C, f = 1MHz$	
	T + 1 0 '' 0	00	,		$V_R = 800V, I_F = 10A$	F: 4
Q_{C}	Total Capacitive Charge	29	/	nC	di/dt = 200A/µs, T _J = 25°C	Fig.4

Thermal Characteristics

Symbol	Parameter	Тур.	Unit	Note
R _{θJC}	Thermal Resistance from Junction to Case	1* 0.5**	°C/W	Fig.6
R _{θJA}	R _{θJA} Thermal Resistance from Junction to Ambient		°C/W	
T _{sold} Soldering Temperature		260	°C	

^{*}Per Leg, **Per Device

Typical Performance (Per Leg)



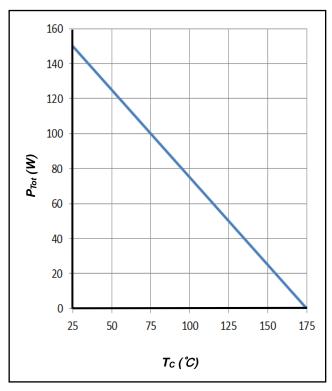
100 90 80 70 60 **-**25°C •75°C 40 •125°C 30 •175°C 20 10 200 400 600 800 1000 1200 1400 $V_R(V)$

Figure 1. Forward Characteristics

Figure 2. Reverse Characteristics

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Typical Performance (Per Leg)



35 30 25 20 20 15 10 5 0 200 400 600 800 1000 1200 V_R (V)

Figure 3. Power Derating

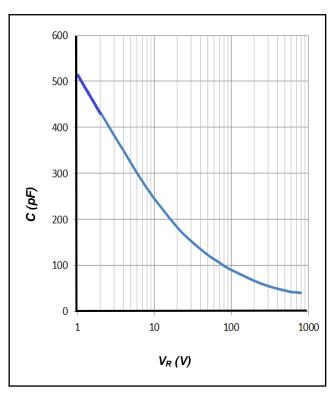


Figure 5. Total Capacitance vs. Reverse Voltage

Figure 4. Total Capacitive Charge vs. Reverse Voltage

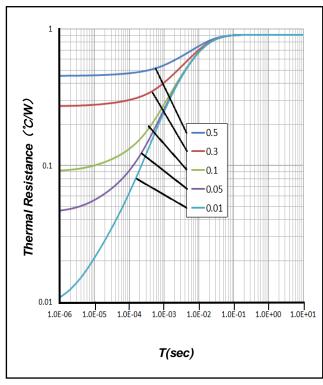
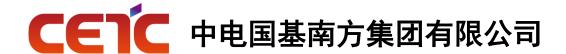
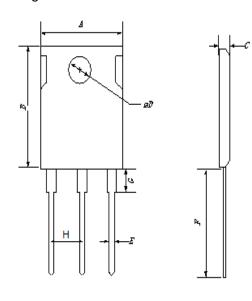


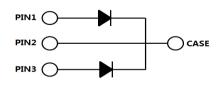
Figure 6. Transient Thermal Impedance



Package Dimensions

Package TO-247-3

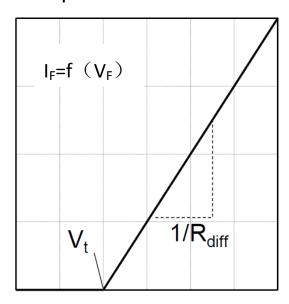




Symbol	Min. (mm)	Typ. (mm)	Max. (mm)	
Α	14.18	15.75	17.33	
В	18.45	20.5	22.55	
С	4.50	5.00	5.50	
D	3.15	3.50	3.85	
E	1.08	1.20	1.32	
F	18.27	20.30	22.33	
G	4.21	4.68	5.15	
Н	4.91	5.46	6.01	

Simplified Diode Model (Per Leg)

Equivalent IV Curve for Model



Mathematical Equation(Per Leg)

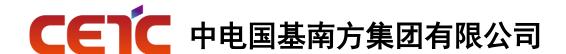
$$V_F = V_t + I_F \times R_{diff}$$

Less than 20A

$$\begin{split} V_t &= -0.0012 \textbf{x} T_j + 0.9952 \ [V] \\ R_{diff} &= 2 \textbf{x} 10^{-6} \textbf{x} T_j^2 + 1 \textbf{x} 10^{-4} \textbf{x} T_j + 0.0579 \ [\Omega] \end{split}$$

Note:

 $Tj = \mbox{Diode Junction Temperature In Degrees Celsius,} \\ \mbox{valid from } 25^{\circ}\mbox{C to } 175^{\circ}\mbox{C} \\ \mbox{I}_{\mbox{F}} = \mbox{Forward Current} \\ \mbox{}$



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